CMOS Digital Integrated Circuits Silicon Monolithic

# 74VHCT240AFT,74VHCT244AFT

#### 1. Functional Description

· Octal Bus Buffer

74VHCT240AFT: INVERTED, 3-STATE OUTPUTS 74VHCT244AFT: NON-INVERTED, 3-STATE OUTPUTS

#### 2. General

The 74VHCT240AFT and 74VHCT244AFT are advanced high speed CMOS OCTAL BUS BUFFERs fabricated with silicon gate C<sup>2</sup>MOS technology. They achieve the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The 74VHCT240AFT is an inverting 3-state buffer having two active-low output enables. The 74VHCT244AFT is a non-inverting 3-state buffer, and has two active-low output enables.

These devices are designed to be used with 3-state memory address drivers, etc.

The input voltage are compatible with TTL output voltage.

These devices may be used as a level converter for interfacing 3.3 V to 5 V system.

Input protection and output circuit ensure that 0 to 5.5 V can be applied to the input and output (Note) pins without regard to the supply voltage. These structure prevents device destruction due to mismatched supply and input/output voltages such as battery back up, hot board insertion, etc.

Note: Output in off-state

#### 3. Features

- (1) AEC-Q100 (Rev. H) (Note 1)
- (2) Wide operating temperature range:  $T_{opr} = -40$  to 125 °C
- (3) High speed: Propagation delay time = 6.1 ns (typ.) at  $V_{CC}$  = 5.0 V
- (4) Quiescent supply current:  $I_{CC} = 4.0 \mu A \text{ (max)}$  at  $T_a = 25 \text{ °C}$
- (5) Compatible with TTL input:  $V_{IL} = 0.8 \text{ V (max)}$

$$V_{IH} = 2.0 \text{ V (min)}$$

- (6) Power down protection is provided on all inputs and outputs.
- (7) Balanced propagation delays:  $t_{PLH} \approx t_{PHL}$
- (8) Low noise:  $V_{OLP} = 1.0 \text{ V (max)}$
- (9) Pin and function compatible with the 74 series

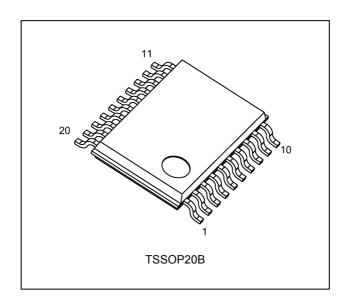
(ACT/HCT/AHCT etc.) 240/244 type.

Note 1: This device is compliant with the reliability requirements of AEC-Q100. For details, contact your Toshiba sales representative.

Rev.4.0

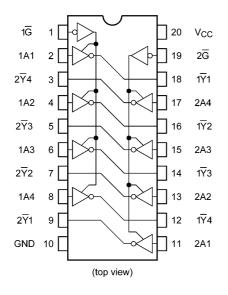


## 4. Packaging

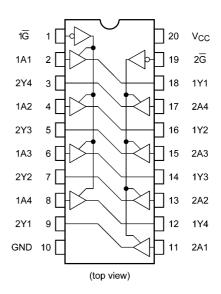


### 5. Pin Assignment

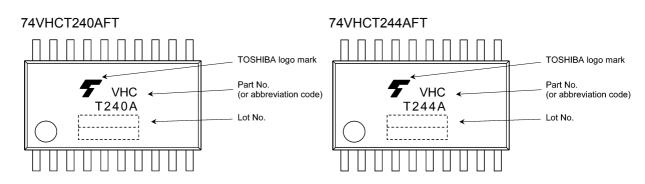
74VHCT240AFT



#### 74VHCT244AFT



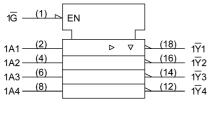
#### 6. Marking

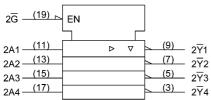




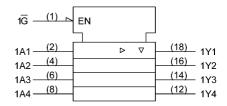
## 7. IEC Logic Symbol

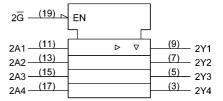
#### 74VHCT240AFT





#### 74VHCT244AFT





#### 8. Truth Table

Input G	Input An	Output Yn	Output $\overline{Y}$ n
L	L	L	Н
L	Н	Н	L
Н	Х	Z	Z

X: Don't careZ: High impedanceYn: 74VHCT244AFTYn: 74VHCT240AFT



### 9. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V <sub>CC</sub>		-0.5 to 7.0	V
Input voltage	V <sub>IN</sub>		-0.5 to 7.0	V
Output voltage	V <sub>OUT</sub>	(Note 1)	-0.5 to 7.0	V
		(Note 2)	-0.5 to V <sub>CC</sub> + 0.5	
Input diode current	I <sub>IK</sub>		-20	mA
Output diode current	I <sub>OK</sub>	(Note 3)	±20	mA
Output current	I <sub>OUT</sub>		±25	mA
V <sub>CC</sub> /ground current	I <sub>CC</sub>		±75	mA
Power dissipation	P <sub>D</sub>	(Note 4)	180	mW
Storage temperature	T <sub>stg</sub>		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Output in off-state.

Note 2: High (H) or Low (L) state. IOUT absolute maximum rating must be observed.

Note 3: V<sub>OUT</sub> < GND, V<sub>OUT</sub> > <sub>VCC</sub>

Note 4: 180 mW in the range of  $T_a$  = -40 to 85 °C. From  $T_a$  = 85 to 125 °C a derating factor of -3.25 mW/°C shall be applied until 50 mW.

### 10. Operating Ranges (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V <sub>CC</sub>		4.5 to 5.5	V
Input voltage	V <sub>IN</sub>		0 to 5.5	V
Output voltage	V <sub>OUT</sub>	(Note 1)	0 to 5.5	V
		(Note 2)	0 to V <sub>CC</sub>	
Operating temperature	T <sub>opr</sub>		-40 to 125	°C
Input rise and fall times	dt/dv		0 to 20	ns/V

Note: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either V<sub>CC</sub> or GND.

Note 1: Output in OFF state.

Note 2: High (H) or Low (L) state.



#### 11. Electrical Characteristics

## 11.1. DC Characteristics (Unless otherwise specified, $T_a = 25$ °C)

Characteristics	Symbol	Test Condition		V <sub>CC</sub> (V)	Min	Тур.	Max	Unit
High-level input voltage	$V_{IH}$	_		4.5 to 5.5	2.0	_		V
Low-level input voltage	$V_{IL}$	_		4.5 to 5.5			0.8	V
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -50 μA	4.5	4.4	4.5		V
			I <sub>OH</sub> = -8 mA	4.5	3.94	_		
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 50 μA	4.5	_	0.0	0.1	V
			I <sub>OL</sub> = 8 mA	4.5	_	_	0.36	
3-state output OFF-state leakage current	I <sub>OZ</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		5.5			±0.25	μА
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0 to 5.5	_	_	±0.1	μΑ
Quiescent supply	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND	'	5.5	_	_	4.0	μΑ
current	I <sub>CCT</sub>	Per input: V <sub>IN</sub> = 3.4V Other input: V <sub>CC</sub> or GND		5.5	_	_	1.35	mA
Output leakage current (Power-OFF)	I <sub>OPD</sub>	V <sub>OUT</sub> = 5.5 V		0	_	_	0.5	μА

## 11.2. DC Characteristics (Unless otherwise specified, T<sub>a</sub> = -40 to 85 °C)

Characteristics	Symbol	Test Condition		V <sub>CC</sub> (V)	Min	Max	Unit
High-level input voltage	V <sub>IH</sub>	_		4.5 to 5.5	2.0	_	V
Low-level input voltage	V <sub>IL</sub>	_		4.5 to 5.5	_	0.8	V
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -50 μA	4.5	4.4	_	V
			$I_{OH}$ = -8 mA	4.5	3.80	_	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 50 μA	4.5	_	0.1	V
			$I_{OL}$ = 8 mA	4.5	_	0.44	
3-state output OFF-state leakage current	I <sub>OZ</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		5.5	_	±2.50	μА
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0 to 5.5	_	±1.0	μΑ
Quiescent supply current	Icc	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	40.0	μА
Quiescent supply current	I <sub>CCT</sub>	Per input: V <sub>IN</sub> = 3.4 V Other input: V <sub>CC</sub> or GND		5.5	_	1.50	mA
Output leakage current (Power-OFF)	I <sub>OPD</sub>	V <sub>OUT</sub> = 5.5 V		0	_	5.0	μА

## 11.3. DC Characteristics (Unless otherwise specified, $T_a$ = -40 to 125 °C)

Characteristics	Symbol	Test Condition		V <sub>CC</sub> (V)	Min	Max	Unit
High-level input voltage	V <sub>IH</sub>	_		4.5 to 5.5	2.0	_	V
Low-level input voltage	V <sub>IL</sub>	_		4.5 to 5.5	_	0.8	V
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -50 μA	4.5	4.4	_	V
			$I_{OH}$ = -8 mA	4.5	3.70	_	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 50 μA	4.5	_	0.1	V
			I <sub>OL</sub> = 8 mA	4.5	_	0.55	
3-state output OFF-state leakage current	I <sub>OZ</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$			_	±10.0	μА
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0 to 5.5	_	±2.0	μА
Quiescent supply current	Icc	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	80.0	μА
Quiescent supply current	I <sub>CCT</sub>	Per input: V <sub>IN</sub> = 3.4 V Other input: V <sub>CC</sub> or GND		5.5	_	1.50	mA
Output leakage current (Power-OFF)	I <sub>OPD</sub>	V <sub>OUT</sub> = 5.5 V		0	_	20.0	μА



## 11.4. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Part Number	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Тур.	Max	Unit
Propagation delay time	74VHCT240AFT	$t_{PLH}, t_{PHL}$		_	$5.0 \pm 0.5$	15	_	5.6	7.8	ns
						50	_	6.1	8.8	
	74VHCT244AFT	t <sub>PLH</sub> ,t <sub>PHL</sub>		_	$5.0 \pm 0.5$	15	_	5.4	7.4	ns
						50	_	5.9	8.4	
3-state output enable time		$t_{PZL}, t_{PZH}$		$R_L = 1 k\Omega$	$5.0 \pm 0.5$	15	_	7.7	10.4	ns
						50	_	8.2	11.4	
3-state output disable time		$t_{PLZ}, t_{PHZ}$		$R_L = 1 k\Omega$	$5.0 \pm 0.5$	50	_	8.8	11.4	ns
Output skew		$t_{osLH}, t_{osHL}$	(Note 1)	_	$5.0 \pm 0.5$	50	_	_	1.0	ns
Input capacitance		C <sub>IN</sub>		_			_	4	10	pF
Output capacitance		C <sub>OUT</sub>		_			_	9	_	pF
Power dissipation	74VHCT240AFT	$C_{PD}$	(Note 2)	_		·		19	_	pF
capacitance	74VHCT244AFT	$C_{PD}$	(Note 2)	_			_	18	_	

Note 1: Parameter guaranteed by design.  $(t_{osLH} = |t_{PLH}m-t_{PLH}n|, t_{osHL} = |t_{PHL}m-t_{PHL}n|)$ 

Note 2:  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

 $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/8$  (per bit)

# 11.5. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_f = t_f = 3$ ns)

Characteristics	Part Number	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Max	Unit
Propagation delay time	74VHCT240AFT	$t_{PLH}, t_{PHL}$		_	$5.0 \pm 0.5$	15	1.0	9.0	ns
						50	1.0	10.0	
	74VHCT244AFT	$t_{PLH}, t_{PHL}$		_	5.0 ± 0.5	15	1.0	8.5	ns
						50	1.0	9.5	
3-state output enable time		$t_{PZL}, t_{PZH}$		$R_L = 1 k\Omega$	$5.0 \pm 0.5$	15	1.0	12.0	ns
						50	1.0	13.0	
3-state output disable time		$t_{PLZ}, t_{PHZ}$		$R_L = 1 k\Omega$	$5.0 \pm 0.5$	50	1.0	13.0	ns
Output skew		$t_{osLH}, t_{osHL}$	(Note 1)	_	$5.0 \pm 0.5$	50		1.0	ns
Input capacitance		C <sub>IN</sub>						10	pF

Note 1: Parameter guaranteed by design.  $(t_{osLH} = |t_{PLH}m-t_{PLH}n|, t_{osHL} = |t_{PHL}m-t_{PHL}n|)$ 

# 11.6. AC Characteristics (Unless otherwise specified, $T_a$ = -40 to 125 °C, Input: $t_r$ = $t_f$ = 3 ns)

Characteristics	Part Number	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Max	Unit
Propagation delay time	74VHCT240AFT	$t_{PLH}, t_{PHL}$		_	$5.0 \pm 0.5$	15	1.0	10.0	ns
						50	1.0	11.0	
Propagation delay time	74VHCT244AFT	$t_{PLH}, t_{PHL}$		_	$5.0 \pm 0.5$	15	1.0	9.5	ns
						50	1.0	10.5	
3-state output enable time		$t_{PZL}, t_{PZH}$		$R_L = 1 k\Omega$	$5.0 \pm 0.5$	15	1.0	13.0	ns
						50	1.0	14.5	
3-state output disable time		$t_{PLZ}, t_{PHZ}$		$R_L = 1 k\Omega$	$5.0 \pm 0.5$	50	1.0	14.5	ns
Output skew		$t_{osLH}, t_{osHL}$	(Note 1)	_	$5.0 \pm 0.5$	50	-	1.0	ns
Input capacitance		C <sub>IN</sub>		_			_	10	pF

Note 1: Parameter guaranteed by design.  $(t_{osLH} = |t_{PLH}m-t_{PLH}n|, t_{osHL} = |t_{PHL}m-t_{PHL}n|)$ 



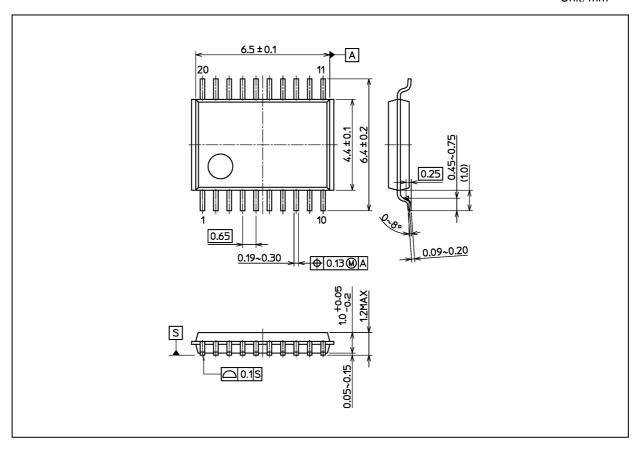
# 11.7. Noise Characteristics (Unless otherwise specified, $T_a$ = 25 °C, Input: $t_r$ = $t_f$ = 3 ns)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Тур.	Limit	Unit
Quiet output maximum dynamic V <sub>OL</sub>	V <sub>OLP</sub>	C <sub>L</sub> = 50 pF	5.0	0.8	1.0	V
Quiet output minimum dynamic V <sub>OL</sub>	V <sub>OLV</sub>	C <sub>L</sub> = 50 pF	5.0	-0.8	-1.0	
Minimum high-level dynamic input voltage	V <sub>IHD</sub>	C <sub>L</sub> = 50 pF	5.0		2.0	
Maximum low-level dynamic input voltage	$V_{ILD}$	C <sub>L</sub> = 50 pF	5.0		0.8	



## **Package Dimensions**

Unit: mm



Weight: 0.071 g (typ.)

	Package Name(s)
Nickname: TSSOP20B	



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